**ON Semiconductor** 

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# Onsemi

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# General Purpose Transistors

**NPN Silicon** 

# **BC846ALT1G Series**

### Features

- Moisture Sensitivity Level: 1
- ESD Rating Human Body Model: > 4000 V – Machine Model: > 400 V
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

# MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC846 BC847, BC850 BC848, BC849	V <sub>CEO</sub>	65 45 30	Vdc
Collector-Base Voltage BC846 BC847, BC850 BC848, BC849	V <sub>CBO</sub>	80 50 30	Vdc
Emitter-Base Voltage BC846 BC847, BC850 BC848, BC849	V <sub>EBO</sub>	6.0 6.0 5.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C	P <sub>D</sub>	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\thetaJA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T <sub>A</sub> = 25°C	P <sub>D</sub>	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

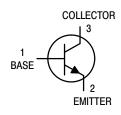


2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in 99.5% alumina.



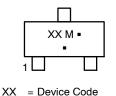
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# MARKING DIAGRAM



M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

# ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

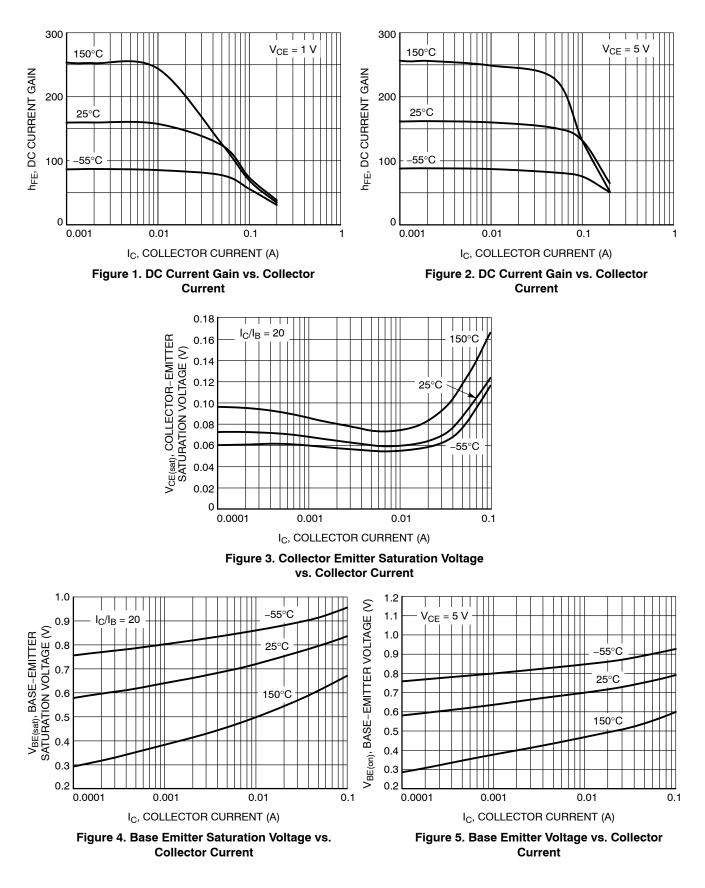
# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Character	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•		•	-	
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)CEO</sub>	65 45 30	- - -	- - -	V
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 $\mu$ A, V <sub>EB</sub> = 0)	BC846A, B, C BC847A, B, C BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)CES</sub>	80 50 30	- - -	- - -	V
Collector – Base Breakdown Voltage ( $I_C = 10 \ \mu A$ )	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)CBO</sub>	80 50 30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 1.0 $\mu$ A)	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)EBO</sub>	6.0 6.0 5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = 30 V) (V <sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)		I <sub>CBO</sub>	-		15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V)	BC846A, BC847A, BC848A BC846B, BC847B, BC848B BC846C, BC847C, BC848C	h <sub>FE</sub>	- - -	90 150 270	- - -	_
(I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V) BC846C, B	BC846A, BC847A, BC848A BC846B, BC847B, BC848B, BC849B, BC850B C847C, BC848C, BC849C, BC850C		110 200 420	180 290 520	220 450 800	
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)				_ _	0.25 0.6	V
Base – Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)			-	0.7 0.9		V
Base – Emitter Voltage (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V)			580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product			100	-	-	MHz

Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$ )		f <sub>T</sub>	100	-	-	MHz	
Output Capacitance (V <sub>CB</sub> = 10 V,	f = 1.0 MHz)	C <sub>obo</sub>	-	-	4.5	pF	
Noise Figure (I <sub>C</sub> = 0.2 mA, $V_{CE}$ = 5.0 Vdc, R <sub>S</sub> = 2.0 k $\Omega$ , f = 1.0 kHz, BW = 200 Hz)	BC846A,B,C, BC847A,B,C, BC848A,B,C BC849B,C, BC850B,C	NF	-	-	10 4.0	dB	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### BC846A, BC847A, BC848A, SBC846A



# BC846A, BC847A, BC848A, SBC846A

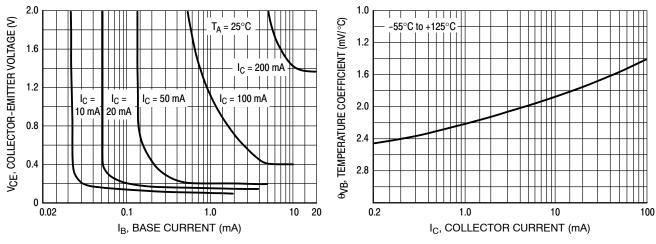


Figure 6. Collector Saturation Region

Figure 7. Base-Emitter Temperature Coefficient

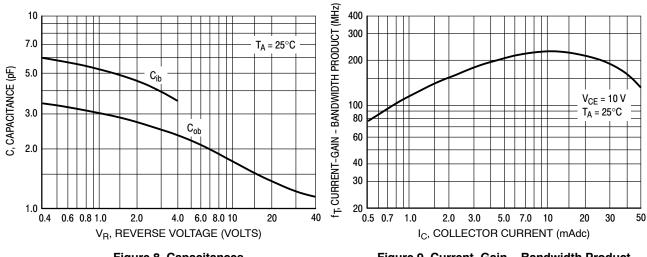
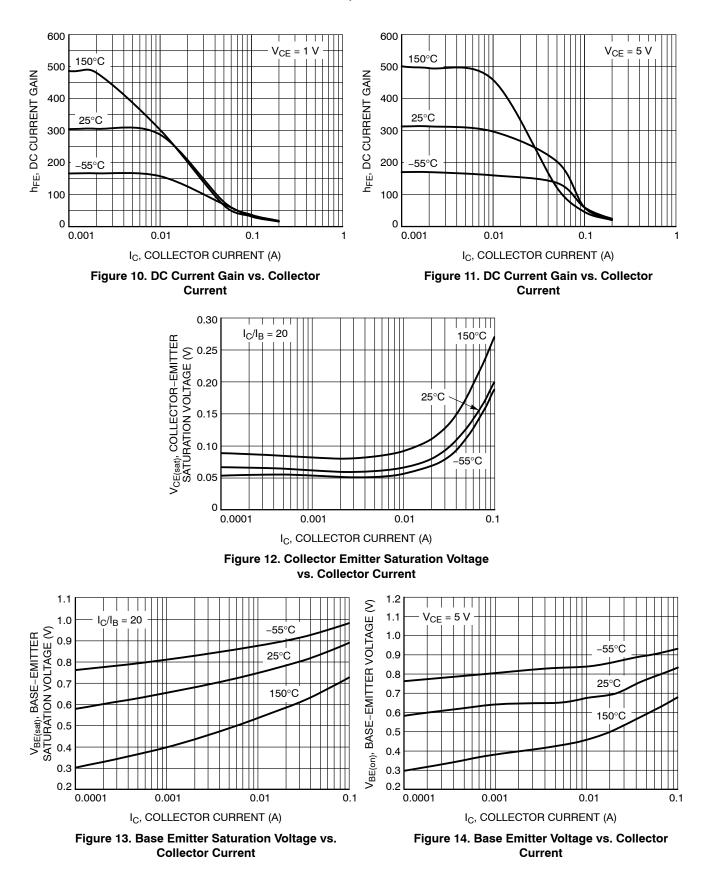


Figure 8. Capacitances

Figure 9. Current–Gain – Bandwidth Product

#### BC846B, SBC846B



#### BC846B, SBC846B

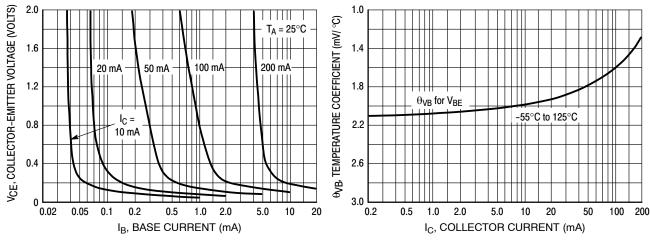


Figure 15. Collector Saturation Region

Figure 16. Base-Emitter Temperature Coefficient

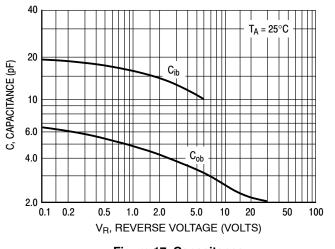


Figure 17. Capacitance

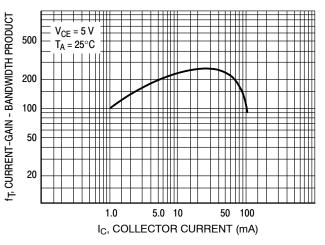
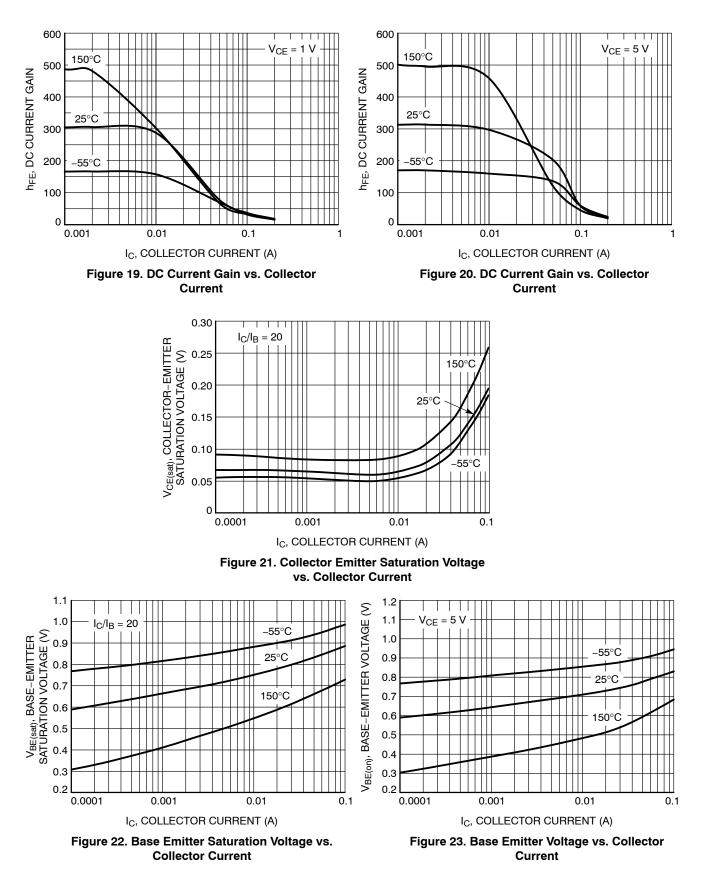
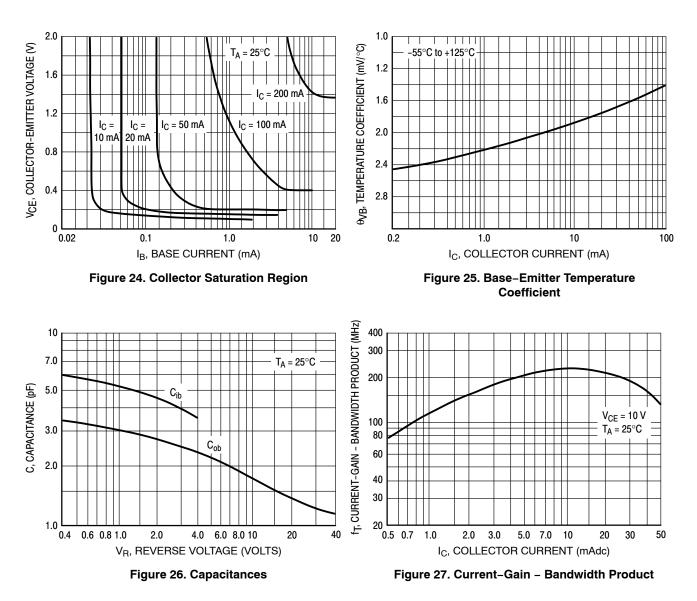


Figure 18. Current–Gain – Bandwidth Product

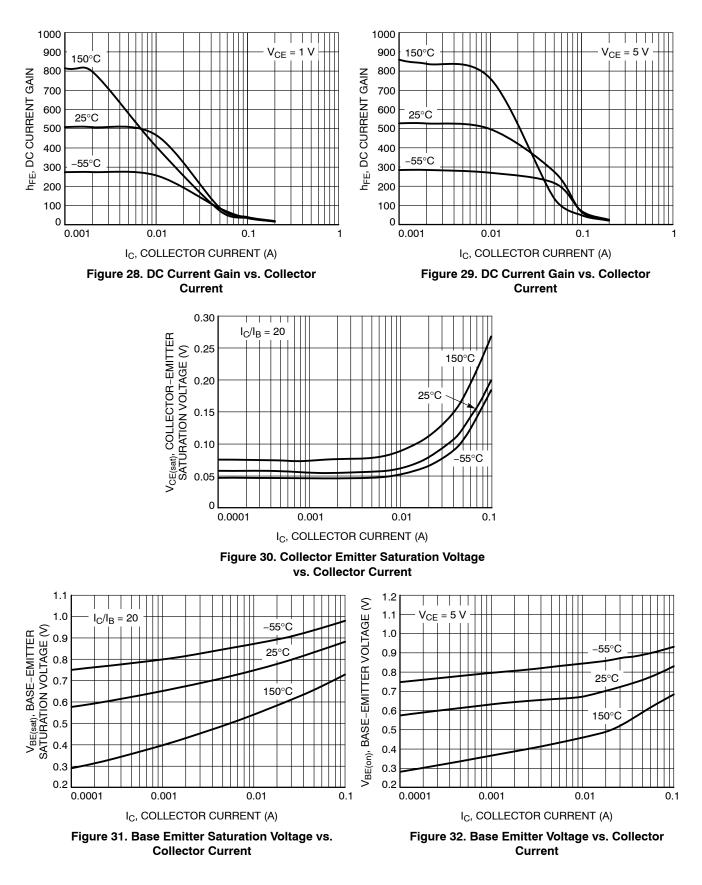
# BC847B, BC848B, BC849B, BC850B, SBC847B, SBC848B



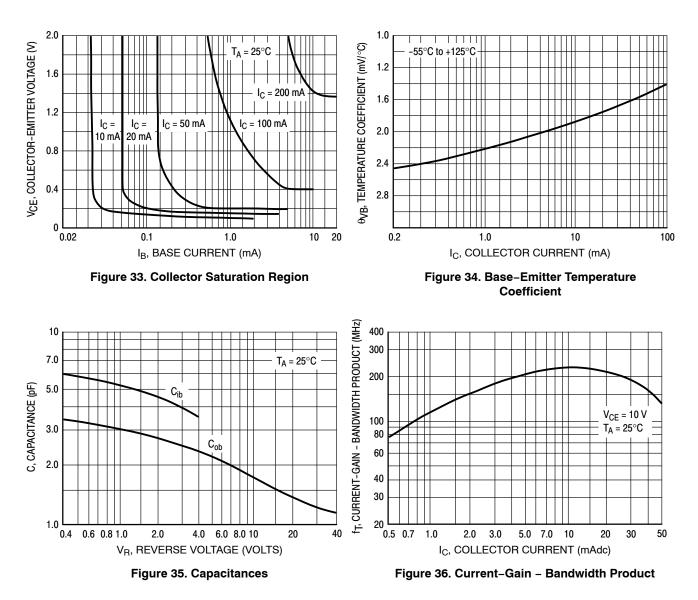
# BC847B, BC848B, BC849B, BC850B, SBC846B, SBC847B, SBC848B

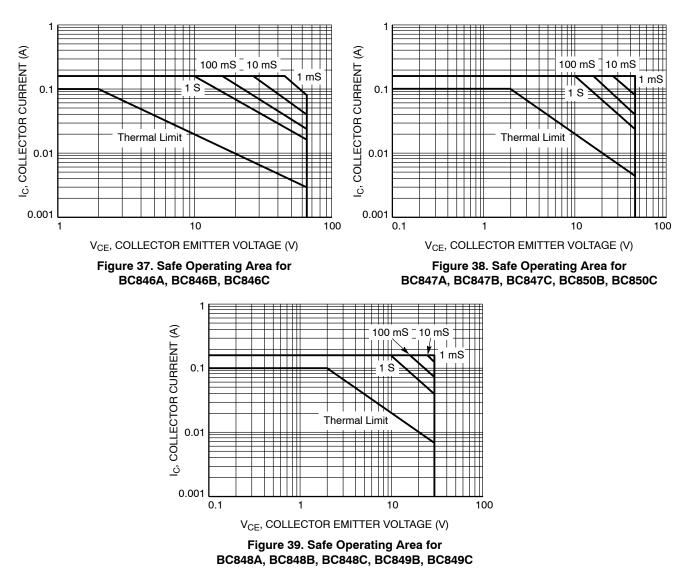


# BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C



# BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C





#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>			
BC846ALT1G						
SBC846ALT1G*	1A	,	3,000 / Tape & Reel			
BC846ALT3G			10,000 / Tape & Reel			
BC846BLT1G			2 000 / Tana & Daal			
SBC846BLT1G*			3,000 / Tape & Reel			
BC846BLT3G						
SBC846BLT3G*			10,000 / Tape & Reel			
BC846CLT1G	ЗC		3,000 / Tape & Reel			
BC847ALT1G			3,000 / Tape & Reel			
BC847ALT3G	1E		10,000 / Tape & Reel			
BC847BLT1G		1				
SBC847BLT1G*	15	-	3,000 / Tape & Reel			
BC847BLT3G	1F					
NSVBC847BLT3G*			10,000 / Tape & Reel			
BC847CLT1G						
SBC847CLT1G*	1G		3,000 / Tape & Reel			
BC847CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel			
BC848ALT1G	1J		3,000 / Tape & Reel			
BC848BLT1G						
SBC848BLT1G*	1K		3,000 / Tape & Reel			
BC848BLT3G			10,000 / Tape & Reel			
BC848CLT1G						
NSVBC848CLT1G*	1L		3,000 / Tape & Reel			
BC848CLT3G		-	10,000 / Tape & Reel			
BC849BLT1G						
NSVBC849BLT1G*	2B		3,000 / Tape & Reel			
BC849BLT3G			10,000 / Tape & Reel			
BC849CLT1G	~~~	1	3,000 / Tape & Reel			
BC849CLT3G	2C		10,000 / Tape & Reel			
BC850BLT1G	25	1				
NSVBC850BLT1G*	2F					
BC850CLT1G	~~~	1	3,000 / Tape & Reel			
NSVBC850CLT1G*	2G					

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.





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